

Features

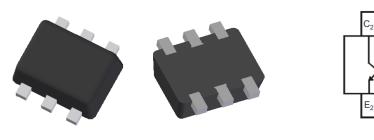
- BV_{CEO} > 40V
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Complementary PNP Type: MMDT2907VQ
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DIODES™ MMDT2222VQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

SOT563

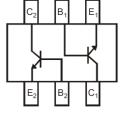
Mechanical Data

- Package: SOT563
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.003 grams (Approximate)



Top View

Bottom View



Device Schematic Top View

Ordering Information (Note 4)

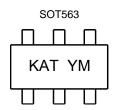
Product	Package	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
MMDT2222VQ-7	SOT563	KAT	7	8	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



KAT = Product Type Marking Code YM = Date Code Marking Y = Year (ex: J = 2022) M = Month (ex: 9 = September)

Date Code Key

Year	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	J	К	L	М	Ν	0	Р	R	S	Т	U	V
	-		_			-			-	-	-	-
	-				1	-			_	-		_
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	75	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Current	I _C	600	mA

Thermal Characteristics

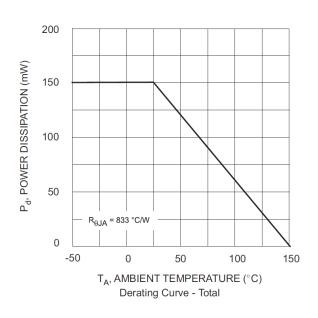
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	150	mW
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	833	°C/W
Operating and Storage and Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device Notes: is measured when operating in a steady-state condition.
Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristic and Derating Information





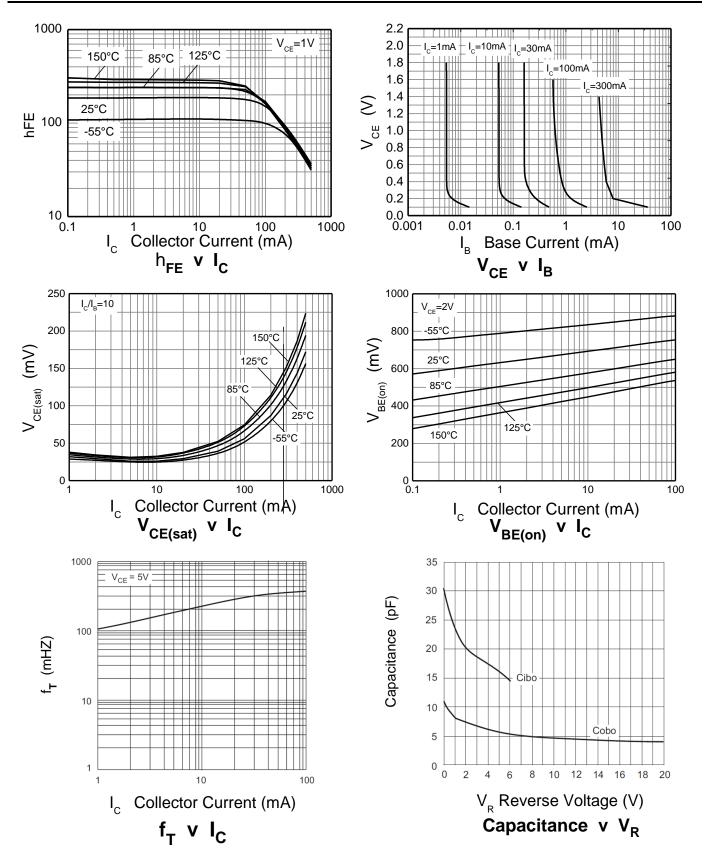
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Мах	Unit	Test Condition
OFF CHARACTERISTICS					
Collector-Base Breakdown Voltage	BV _{CBO}	75		V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 7)	BV _{CEO}	40		V	$I_{\rm C} = 10 {\rm mA}$
Emitter-Base Breakdown Voltage	BV _{EBO}	6		V	I _E = 100μA
			10	nA	$V_{CB} = 60V$
Collector-Base Cut-Off Current	I _{CBO}		10	μA	V _{CB} = 60V, T _A = +150°C
Collector Cut-Off Current	I _{CEX}	_	10	nA	$V_{CE} = 60V, V_{BE(off)} = 3V$
Emitter-Base Cut-Off Current	I _{EBO}	_	10	nA	V _{EB} = 5V
Base Cut-Off Current	I _{BL}	_	20	nA	$V_{CE} = 60V, V_{BE(off)} = 0V$
ON CHARACTERISTICS (Note 7)					
		35			$I_{C} = 100 \mu A, V_{CE} = 10 V$
		50			$I_{C} = 1mA, V_{CE} = 10V$
		75			$I_{C} = 10 \text{mA}, V_{CE} = 10 \text{V}$
DC Current Gain	h _{FE}	100	300		$I_{C} = 150 \text{mA}, V_{CE} = 10 \text{V}$
		40			$I_{C} = 500 \text{mA}, V_{CE} = 10 \text{V}$
		50			$I_{C} = 10 \text{mA}, V_{CE} = 10 \text{V}, T_{A} = -55^{\circ}\text{C}$
		35			I _C = 150mA, V _{CE} = 1V
Collector Emitter Seturation Valence	V		0.3	0.3 V	I _C = 150mA, I _B = 15mA
Collector-Emitter Saturation Voltage	V _{CE(sat)}		1.0	v	I _C = 500mA, I _B = 50mA
Doos Emitter Seturation Voltage		0.6	1.2	V	I _C = 150mA, I _B = 15mA
Base-Emitter Saturation Voltage	V _{BE(sat)}	_	2.0	V	I _C = 500mA, I _B = 50mA
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C _{obo}	_	8.0	рF	$V_{CB} = 10V, f = 1MHz, I_E = 0$
Input Capacitance	C _{ibo}	_	25	pF	$V_{EB} = 0.5V, f = 1MHz, I_{C} = 0$
Current Cain Dan duidth Dan duat	ſ	200		N 41 1-	$V_{CE} = 20V, I_{C} = 20mA,$
Current Gain-Bandwidth Product	f _T	300		MHz	f = 100MHz
Noise Figure			4	dB	$V_{CE} = 10V, I_{C} = 100 \mu A,$
Noise Figure	NF	_	4	aв	$R_S = 1k\Omega$, f = 1.0kHz
SWITCHING CHARACTERISTICS					
Delay Time	t _d	_	10	ns	$V_{CC} = 30V, I_C = 150mA,$
Rise Time	tr	_	25	ns	$V_{BE(off)} = -0.5V, I_{B1} = 15mA$
Storage Time	t _s	_	225	ns	$V_{CC} = 30V, I_C = 150mA,$
Fall Time	t _f	_	60	ns	I _{B1} =-I _{B2} = 15mA

Note: 7. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



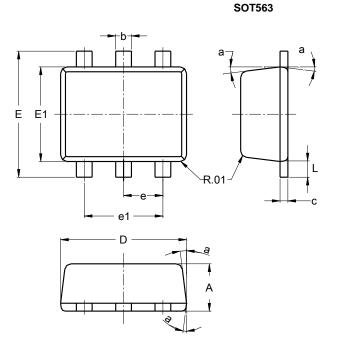
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

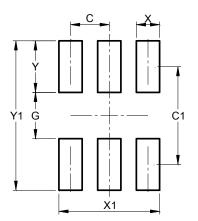


SOT563					
Dim	Min	Max	Тур		
Α	0.55	0.60			
b	0.15	0.30	0.20		
С	0.10	0.18	0.11		
D	1.50	1.70	1.60		
Е	1.55	1.70	1.60		
E1	1.10	1.25	1.20		
е			0.50		
e1	0.90	1.10	1.00		
L	0.10	0.30	0.20		
а	8°	9°	7°		
All	All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT563



Dimensions	Value (in mm)		
С	0.500		
C1	1.270		
G	0.600		
Х	0.300		
X1	1.300		
Y	0.670		
Y1	1.940		

MMDT2222VQ Document number: DS44337 Rev. 1 - 2



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